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INFORMATION DISCLOSURE STATEMENT
IN A PATENT
(use several sheets if necessary)

Docket No. P97,0027	Serial No. 08/818,239
Applicant Hiroshi Tayanaka	
Filing Date March 14, 1997	Group Art Unit 2813

U.S. PATENT DOCUMENTS

Examiner's Initials	Document Number	Date	Name	Class	Subclass	Filing Date If appropriate
AA						RECEIVED
AB						MAY 18 1999
AE						TECHNOLOGY CENTER 2800
AD						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation Yes No
XC	AE	EP 0 554 795 A1	Aug. 11, 1993	EPO	—	—	X
XC	AF	EP 0 793 263 A2	Sept. 3, 1997	EPO	—	—	X
	AG						
	AH						
	AE						
	AJ						
	AK						

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

XC	AL	Patent Abstracts of Japan, Vol. 010, No. 039 (E-381), 15 February 1986 & JP 60 196955 A (TOKO INC), 5 October 1985
XC	AM	T. Yasumatsu, et al., "Ultrathin Si films grown epitaxially on porous silicon", Applied Surface Science, Vol. 48/49, May 1991, pages 414-418, XP-002093161
XC	AN	M. Ohnishi, et al., "NEW TYPE STRUCTURES OF A-SI SOLAR CELL SUBMODULES FABRICATED BY MICROSCOPIC HOLE SPACING TECHNIQUE", RECORD OF THE PHOTOVOLTAIC SPECIALISTS CONFERENCE, KISSIMIMEE, May 21- 25, 1990, Vol. 2, No. CONF. 21, 21 May 1990, pages 1394-1399, XP 000480389, INSTITUTE OF ELECTRICAL AND ELECTRONICS ENGINEERS
XC	AO	Patent Abstracts of Japan, Vol. 018, No. 066 (E-1501), 3 February 1994, & JP 05 283722 (CANON INC), 29 October 1993

Examiner *K. Setton* Date Considered *5/21/99*

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.